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APPLICATION NO.		FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
09/922,804		08/07/2001	Michikazu Matsumoto	740819-610	8887
22204	7590	07/17/2002			
NIXON PE	ABODY	, LLP	EXAMINER		
8180 GREENSBORO DRIVE SUITE 800				ERDEM, FAZLI	
MCLEAN, VA 22102)2		ART UNIT	PAPER NUMBER
				2826	1 _
				DATE MAILED: 07/17/2002	7

Please find below and/or attached an Office communication concerning this application or proceeding.

• • • •	Application No.	Applicant(s)				
	09/922,804	MATSUMOTO ET AL.				
Office Action Summary	Examiner	Art Unit				
	Fazli Erdem	2826				
The MAILING DATE of this communication app Period for Reply	ears on the cover sheet with the c	orrespondence address				
A SHORTENED STATUTORY PERIOD FOR REPLY THE MAILING DATE OF THIS COMMUNICATION. - Extensions of time may be available under the provisions of 37 CFR 1.13 after SIX (6) MONTHS from the mailing date of this communication. - If the period for reply specified above is less than thirty (30) days, a reply - If NO period for reply is specified above, the maximum statutory period w. - Failure to reply within the set or extended period for reply will, by statute, - Any reply received by the Office later than three months after the mailing earned patent term adjustment. See 37 CFR 1.704(b). Status	86(a). In no event, however, may a reply be time within the statutory minimum of thirty (30) day rill apply and will expire SIX (6) MONTHS from cause the application to become ABANDONE	nely filed s will be considered timely. the mailing date of this communication. D (35 U.S.C. § 133).				
1) Responsive to communication(s) filed on <u>07 A</u>	<u>ugust 2001</u> .					
2a) ☐ This action is FINAL . 2b) ☑ Thi	s action is non-final.					
 Since this application is in condition for allowa closed in accordance with the practice under labels Disposition of Claims 						
4) Claim(s) 1-10 is/are pending in the application						
4a) Of the above claim(s) is/are withdraw	vn from consideration.					
5) Claim(s) is/are allowed.						
6)⊠ Claim(s) <u>1-5, 6-9</u> is/are rejected.						
7)⊠ Claim(s) <u>6 and 10</u> is/are objected to.						
8) Claim(s) are subject to restriction and/or	election requirement.					
Application Papers						
9) The specification is objected to by the Examiner						
10) The drawing(s) filed on is/are: a) accep	•					
Applicant may not request that any objection to the 11) The proposed drawing correction filed on						
		ved by the Examiner.				
If approved, corrected drawings are required in reply to this Office action. 12) The oath or declaration is objected to by the Examiner.						
Priority under 35 U.S.C. §§ 119 and 120						
13) Acknowledgment is made of a claim for foreign	priority under 35 H S C & 119/a	\-(d\ or (f)				
a)⊠ All b)□ Some * c)□ None of:	priority under ou o.o.o. 3 1 rola	, (a) 5. (.).				
1. ☐ Certified copies of the priority documents	s have been received					
2. Certified copies of the priority documents		on No				
Copies of the certified copies of the prior application from the International Bur	ity documents have been receive eau (PCT Rule 17.2(a)).	ed in this National Stage				
* See the attached detailed Office action for a list of	•					
14) Acknowledgment is made of a claim for domestic	•					
 a) The translation of the foreign language pro- 15) Acknowledgment is made of a claim for domestic 	• •					
Attachment(s)						
1) Notice of References Cited (PTO-892) 2) Notice of Draftsperson's Patent Drawing Review (PTO-948) 3) Information Disclosure Statement(s) (PTO-1449) Paper No(s)	5) Notice of Informal F	(PTO-413) Paper No(s) Patent Application (PTO-152)				

DETAILED ACTION

Allowable Subject Matter

1. Claims 6 and 10 are objected to as being dependent upon a rejected base claim, but would be allowable if rewritten in independent form including all of the limitations of the base claim and any intervening claims.

Claim Rejections - 35 USC § 102

The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

(b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.

2. Claims 1, 3-5 are rejected under 35 U.S.C. 102(b) as being anticipated by Agarwal (6, 218,256).

Regarding Claim 1, Fig. 7 of Agarwal shows an electrode and capacitor structure for a semiconductor device where detail 10 is the substratrate, followed by polysilicon layer 48, insulating layer 14, Titanium nitride barrier layer 16 and a high melting point conductive layer 18.

Regarding Claim3-5, in columns 10-12, Agarwal discloses the method of making an electrode and capacitor structure of Fig. 7.

Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

- (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 3. Claims 2, 7-9 are rejected under 35 U.S.C. 103(a) as being unpatentable over Nagasaka et al. (5,973,408) in view of Ito et al. (5,561,326).

Regarding Claim 2, Fig. 1 of Nagasaka et al. show an electrode structure for a semiconductor device where two titanium nitride films 261A and 261B are located above a protective films 35 and 34. An electrode wiring 151 is positioned above the two titanium nitride structures 261A and 261B. Nagasaka does not show the second titanium nitride structure to have a higher nitride structure. However, Ito et al. show a large scale integrated circuit device where in Fig. 2 two titanium structures 186 and 187 a located. Ito et al. further disclose that the second titanium nitride structure has a higher nitride ratio.

Regarding Claims 7-9, Figs. 1-4 of Nagasaka et al. and the Figs. 1-10 of Ito et al. show a method of making an electrode structure with two titanium nitride layers one with the second titanium nitride layer having a higher concentration of nitride.

It would have been obvious to one of having ordinary skill in the art at the time the invention was made to have a two titanium nitride layers with the second titanium nitride layer having a higher concentration of nitride in Nagasaka et al. as taught by Ito et al. because such structure would provide a better insulation.

Conclusion

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Any inquiry concerning this communication or earlier communications from the examiner should be directed to Fazli Erdem whose telephone number is (703) 305-3868. The examiner can normally be reached on M - F 8:00 - 5:00.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Nathan Flynn can be reached on (703) 308-6601. The fax phone numbers for the organization where this application or proceeding is assigned are (703) 308-7722 for regular communications and (703) 308-7724 for After Final communications.

Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the receptionist whose telephone number is (703) 308-0956.

FE July 8, 2002

NATHAN J. FLYNN SUPERVISORY PATENT EXAMINER TECHNOLOGY CENTER 2800